



Welcome to [E-XFL.COM](https://www.e-xfl.com)

### **Embedded - System On Chip (SoC): The Heart of Modern Embedded Systems**

**Embedded - System On Chip (SoC)** refers to an integrated circuit that consolidates all the essential components of a computer system into a single chip. This includes a microprocessor, memory, and other peripherals, all packed into one compact and efficient package. SoCs are designed to provide a complete computing solution, optimizing both space and power consumption, making them ideal for a wide range of embedded applications.

### **What are Embedded - System On Chip (SoC)?**

**System On Chip (SoC)** integrates multiple functions of a computer or electronic system onto a single chip. Unlike traditional multi-chip solutions, SoCs combine a central

#### **Details**

Product Status	Active
Architecture	MCU, FPGA
Core Processor	Quad ARM® Cortex®-A53 MPCore™ with CoreSight™, Dual ARM®Cortex™-R5 with CoreSight™, ARM Mali™ -400 MP2
Flash Size	-
RAM Size	256KB
Peripherals	DMA, WDT
Connectivity	CANbus, EBI/EMI, Ethernet, I <sup>2</sup> C, MMC/SD/SDIO, SPI, UART/USART, USB OTG
Speed	500MHz, 600MHz, 1.2GHz
Primary Attributes	Zynq@UltraScale+™ FPGA, 747K+ Logic Cells
Operating Temperature	-40°C ~ 100°C (Tj)
Package / Case	900-BBGA, FCBGA
Supplier Device Package	900-FCBGA (31x31)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/xilinx/xczu15eg-l1ffvc900i">https://www.e-xfl.com/product-detail/xilinx/xczu15eg-l1ffvc900i</a>

**Table 1: Absolute Maximum Ratings<sup>(1)</sup> (Cont'd)**

Symbol	Description	Min	Max	Units
V <sub>CCO_PSDDR</sub>	PS DDR I/O supply voltage.	-0.500	1.650	V
V <sub>CC_PSDDR_PLL</sub>	PS DDR PLL supply voltage.	-0.500	2.000	V
V <sub>CCO_PSIO</sub>	PS I/O supply.	-0.500	3.630	V
V <sub>PSIN</sub> <sup>(2)</sup>	PS I/O input voltage.	-0.500	V <sub>CCO_PSIO</sub> + 0.550	V
	PS DDR I/O input voltage.	-0.500	V <sub>CCO_PSDDR</sub> + 0.550	V
V <sub>CC_PSBATT</sub>	PS battery-backed RAM and battery-backed real-time clock (RTC) supply voltage.	-0.500	2.000	V
<b>Programmable Logic (PL)</b>				
V <sub>CCINT</sub>	Internal supply voltage.	-0.500	1.000	V
V <sub>CCINT_IO</sub> <sup>(3)</sup>	Internal supply voltage for the I/O banks.	-0.500	1.000	V
V <sub>CCAUX</sub>	Auxiliary supply voltage.	-0.500	2.000	V
V <sub>CCBRAM</sub>	Supply voltage for the block RAM memories.	-0.500	1.000	V
V <sub>CCO</sub>	Output drivers supply voltage for HD I/O banks.	-0.500	3.400	V
	Output drivers supply voltage for HP I/O banks.	-0.500	2.000	V
V <sub>CCAUX_IO</sub> <sup>(4)</sup>	Auxiliary supply voltage for the I/O banks.	-0.500	2.000	V
V <sub>REF</sub>	Input reference voltage.	-0.500	2.000	V
V <sub>IN</sub> <sup>(2)(5)(7)</sup>	I/O input voltage for HD I/O banks. <sup>(6)</sup>	-0.550	V <sub>CCO</sub> + 0.550	V
	I/O input voltage for HP I/O banks.	-0.550	V <sub>CCO</sub> + 0.550	V
I <sub>DC</sub>	Available output current at the pad.	-20	20	mA
I <sub>RMS</sub>	Available RMS output current at the pad.	-20	20	mA
<b>GTH or GTY Transceiver</b>				
V <sub>MGTAVCC</sub>	Analog supply voltage for transceiver circuits.	-0.500	1.000	V
V <sub>MGTAVTT</sub>	Analog supply voltage for transceiver termination circuits.	-0.500	1.300	V
V <sub>MGTVCCAUX</sub>	Auxiliary analog Quad PLL (QPLL) voltage supply for transceivers.	-0.500	1.900	V
V <sub>MGTREFCLK</sub>	Transceiver reference clock absolute input voltage.	-0.500	1.300	V
V <sub>MGTAVTTRCAL</sub>	Analog supply voltage for the resistor calibration circuit of the transceiver column.	-0.500	1.300	V
V <sub>IN</sub>	Receiver (RXP/RXN) and transmitter (TXP/TXN) absolute input voltage.	-0.500	1.200	V
I <sub>DCIN-FLOAT</sub>	DC input current for receiver input pins DC coupled RX termination = floating. <sup>(8)</sup>	-	10	mA
I <sub>DCIN-MGTAVTT</sub>	DC input current for receiver input pins DC coupled RX termination = V <sub>MGTAVTT</sub> .	-	10	mA
I <sub>DCIN-GND</sub>	DC input current for receiver input pins DC coupled RX termination = GND. <sup>(9)</sup>	-	0	mA
I <sub>DCIN-PROG</sub>	DC input current for receiver input pins DC coupled RX termination = programmable. <sup>(10)</sup>	-	0	mA
I <sub>DCOUT-FLOAT</sub>	DC output current for transmitter pins DC coupled RX termination = floating.	-	6	mA
I <sub>DCOUT-MGTAVTT</sub>	DC output current for transmitter pins DC coupled RX termination = V <sub>MGTAVTT</sub> .	-	6	mA

Table 2: Recommended Operating Conditions<sup>(1)(2)</sup> (Cont'd)

Symbol	Description	Min	Typ	Max	Units
V <sub>CCO</sub> <sup>(8)</sup>	Supply voltage for HD I/O banks.	1.140	–	3.400	V
	Supply voltage for HP I/O banks.	0.950	–	1.900	V
V <sub>CCAUX_IO</sub> <sup>(9)</sup>	Auxiliary I/O supply voltage.	1.746	1.800	1.854	V
V <sub>IN</sub> <sup>(10)</sup>	I/O input voltage.	–0.200	–	V <sub>CCO</sub> + 0.200	V
I <sub>IN</sub> <sup>(11)</sup>	Maximum current through any PL or PS pin in a powered or unpowered bank when forward biasing the clamp diode.	–	–	10	mA
<b>GTH or GTY Transceiver</b>					
V <sub>MGTAVCC</sub> <sup>(12)</sup>	Analog supply voltage for the GTH or GTY transceiver.	0.873	0.900	0.927	V
V <sub>MGTAVTT</sub> <sup>(12)</sup>	Analog supply voltage for the GTH or GTY transmitter and receiver termination circuits.	1.164	1.200	1.236	V
V <sub>MGTVCCAUX</sub> <sup>(12)</sup>	Auxiliary analog QPLL voltage supply for the transceivers.	1.746	1.800	1.854	V
V <sub>MGTAVTTRCAL</sub> <sup>(12)</sup>	Analog supply voltage for the resistor calibration circuit of the GTH or GTY transceiver column.	1.164	1.200	1.236	V
<b>VCU</b>					
V <sub>CCINT_VCU</sub>	Internal supply voltage for the VCU.	0.825	0.850	0.876	V
	For -1LI and -2LE (V <sub>CCINT</sub> = 0.72V) devices: Internal supply voltage for the VCU.	0.825	0.850	0.876	V
	For -3E devices: Internal supply voltage for the VCU.	0.873	0.900	0.927	V

**Table 2: Recommended Operating Conditions<sup>(1)(2)</sup> (Cont'd)**

Symbol	Description	Min	Typ	Max	Units
<b>PL System Monitor</b>					
V <sub>CCADC</sub>	PL System Monitor supply relative to GNDADC.	1.746	1.800	1.854	V
V <sub>REFP</sub>	PL System Monitor externally supplied reference voltage relative to GNDADC.	1.200	1.250	1.300	V
<b>Temperature</b>					
T <sub>j</sub> <sup>(13)</sup>	Junction temperature operating range for extended (E) temperature devices. <sup>(14)</sup>	0	–	100	°C
	Junction temperature operating range for industrial (I) temperature devices.	–40	–	100	°C
	Junction temperature operating range for eFUSE programming.	–40	–	125	°C

**Notes:**

- All voltages are relative to GND.
- For the design of the power distribution system consult *UltraScale Architecture PCB Design Guide* ([UG583](#)).
- V<sub>CC\_PSINTFP\_DDR</sub> must be tied to V<sub>CC\_PSINTFP</sub>.
- Includes V<sub>CCO\_PSDDR</sub> of 1.2V, 1.35V, 1.5V at ±5% and 1.1V +0.07V/–0.04V depending upon the tolerances required by specific memory standards.
- Applies to all PS I/O supply banks. Includes V<sub>CCO\_PSIO</sub> of 1.8V, 2.5V, and 3.3V at ±5%.
- If the battery-backed RAM or RTC is not used, connect V<sub>CC\_PSBATT</sub> to GND or V<sub>CC\_PSAUX</sub>. The V<sub>CC\_PSAUX</sub> maximum of 1.89V is acceptable on an unused V<sub>CC\_PSBATT</sub>.
- V<sub>CCINT\_IO</sub> must be connected to V<sub>CCBRAM</sub>.
- Includes V<sub>CCO</sub> of 1.0V (HP I/O only), 1.2V, 1.35V, 1.5V, 1.8V, 2.5V (HD I/O only) at ±5%, and 3.3V (HD I/O only) at +3/–5%.
- V<sub>CCAUX\_IO</sub> must be connected to V<sub>CCAUX</sub>.
- The lower absolute voltage specification always applies.
- A total of 200 mA per bank should not be exceeded.
- Each voltage listed requires filtering as described in *UltraScale Architecture GTH Transceiver User Guide* ([UG576](#)) or *UltraScale Architecture GTY Transceiver User Guide* ([UG578](#)).
- Xilinx recommends measuring the T<sub>j</sub> of a device using the system monitor as described in the *UltraScale Architecture System Monitor User Guide* ([UG580](#)). The SYSMON temperature measurement errors (that are described in [Table 69](#) and [Table 124](#)) must be accounted for in your design. For example, when using the PL system monitor with an external reference of 1.25V, when SYSMON reports 97°C, there is a measurement error ±3°C. A reading of 97°C is considered the maximum adjusted T<sub>j</sub> (100°C – 3°C = 97°C).
- Devices labeled with the speed/temperature grade of -2LE normally operate under Extended (E) temperature grade specifications with a maximum junction temperature of 100°C. However, E temperature grade devices can operate for a limited time at a junction temperature of 110°C. Timing parameters adhere to the same speed file at 110°C as they do at 100°C, regardless of operating voltage (nominal voltage of 0.85V or a low-voltage of 0.72V). Operation at T<sub>j</sub> = 110°C is limited to 1% of the device lifetime and can occur sequentially or at regular intervals as long as the total time does not exceed 1% of the device lifetime.

## PS-PL Power Sequencing

The PS and PL power supplies are fully independent. All PS power supplies can be powered before or after any PL power supplies. The PS and PL power regions are isolated to prevent damage.

## Power Supply Requirements

Table 10 shows the minimum current, in addition to  $I_{CCQ}$  maximum, required by each Zynq UltraScale+ device for proper power-on and configuration. If the current minimums shown in Table 10 are met, the device powers on after all supplies have passed through their power-on reset threshold voltages. The device must not be configured until after  $V_{CCINT}$  is applied. Once initialized and configured, use the Xilinx Power Estimator (XPE) tools to estimate current drain on these supplies.

Table 10: Power-on Current by Device<sup>(1)</sup>

$I_{CC}$ Min =	$I_{CCQ}$ +	XCZU2	XCZU3	XCZU4	XCZU5	XCZU6	XCZU7	XCZU9	XCZU11	XCZU15	XCZU17	XCZU19	Units
$I_{CCINTMIN}$	$I_{CCINTQ}^+$	464	464	770	770	1800	1514	1800	1961	2242	3433	3433	mA
$I_{CCINT\_IOMIN}^+$ $I_{CCBRAMMIN}$	$I_{CCBRAMQ}^+$ $I_{CCINT\_IOQ}^+$	155	155	257	257	600	505	600	654	748	1145	1145	mA
$I_{CCOMIN}$	$I_{CCOQ}^+$	50	50	50	50	50	50	50	55	63	96	96	mA
$I_{CCAUXMIN}^+$ $I_{CCAUX\_IOMIN}$	$I_{CCAUXQ}^+$ $I_{CCAUX\_IOQ}^+$	111	111	386	386	650	362	650	709	810	1240	1240	mA

**Notes:**

1. Use the Xilinx Power Estimator (XPE) spreadsheet tool (download at [www.xilinx.com/power](http://www.xilinx.com/power)) to estimate power-on current for all supplies.

Table 11 shows the power supply ramp time.

Table 11: Power Supply Ramp Time

Symbol	Description	Min	Max	Units
$T_{VCCINT}$	Ramp time from GND to 95% of $V_{CCINT}$ .	0.2	40	ms
$T_{VCCINT\_IO}$	Ramp time from GND to 95% of $V_{CCINT\_IO}$ .	0.2	40	ms
$T_{VCCINT\_VCU}$	Ramp time from GND to 95% of $V_{CCINT\_VCU}$ .	0.2	40	ms
$T_{VCCO}$	Ramp time from GND to 95% of $V_{CCO}$ .	0.2	40	ms
$T_{VCCAUX}$	Ramp time from GND to 95% of $V_{CCAUX}$ .	0.2	40	ms
$T_{VCCBRAM}$	Ramp time from GND to 95% of $V_{CCBRAM}$ .	0.2	40	ms
$T_{MGTAVCC}$	Ramp time from GND to 95% of $V_{MGTAVCC}$ .	0.2	40	ms
$T_{MGTAVTT}$	Ramp time from GND to 95% of $V_{MGTAVTT}$ .	0.2	40	ms
$T_{MGTVCCAUX}$	Ramp time from GND to 95% of $V_{MGTVCCAUX}$ .	0.2	40	ms
$T_{VCC\_PSINTFP}$	Ramp time from GND to 95% of $V_{CC\_PSINTFP}$ .	0.2	40	ms
$T_{VCC\_PSINTLP}$	Ramp time from GND to 95% of $V_{CC\_PSINTLP}$ .	0.2	40	ms
$T_{VCC\_PSAUX}$	Ramp time from GND to 95% of $V_{CC\_PSAUX}$ .	0.2	40	ms
$T_{VCC\_PSINTFP\_DDR}$	Ramp time from GND to 95% of $V_{CC\_PSINTFP\_DDR}$ .	0.2	40	ms
$T_{VCC\_PSADC}$	Ramp time from GND to 95% of $V_{CC\_PSADC}$ .	0.2	40	ms
$T_{VCC\_PSPLL}$	Ramp time from GND to 95% of $V_{CC\_PSPLL}$ .	0.2	40	ms
$T_{PS\_MGTRAVCC}$	Ramp time from GND to 95% of $V_{CC\_MGTRAVCC}$ .	0.2	40	ms
$T_{PS\_MGTRAVTT}$	Ramp time from GND to 95% of $V_{CC\_MGTRAVTT}$ .	0.2	40	ms

## AC Switching Characteristics

All values represented in this data sheet are based on the speed specifications in the Vivado® Design Suite as outlined in [Table 25](#).

*Table 25: Speed Specification Version By Device*

2017.1	Device
1.08	XCZU4CG, XCZU4EG, XCZU4EV, XCZU5CG, XCZU5EG, XCZU5EV, XCZU11EG
1.10	XCZU2CG, XCZU2EG, XCZU3CG, XCZU3EG, XCZU6CG, XCZU6EG, XCZU7CG, XCZU7EG, XCZU7EV, XCZU9CG, XCZU9EG, XCZU15EG, XCZU17EG, XCZU19EG

Switching characteristics are specified on a per-speed-grade basis and can be designated as Advance, Preliminary, or Production. Each designation is defined as follows:

### Advance Product Specification

These specifications are based on simulations only and are typically available soon after device design specifications are frozen. Although speed grades with this designation are considered relatively stable and conservative, some under-reporting might still occur.

### Preliminary Product Specification

These specifications are based on complete ES (engineering sample) silicon characterization. Devices and speed grades with this designation are intended to give a better indication of the expected performance of production silicon. The probability of under-reporting delays is greatly reduced as compared to Advance data.

### Product Specification

These specifications are released once enough production silicon of a particular device family member has been characterized to provide full correlation between specifications and devices over numerous production lots. There is no under-reporting of delays, and customers receive formal notification of any subsequent changes. Typically, the slowest speed grades transition to production before faster speed grades.

## Testing of AC Switching Characteristics

Internal timing parameters are derived from measuring internal test patterns. All AC switching characteristics are representative of worst-case supply voltage and junction temperature conditions.

For more specific, more precise, and worst-case guaranteed data, use the values reported by the static timing analyzer and back-annotate to the simulation net list. Unless otherwise noted, values apply to all Zynq UltraScale+ MPSoC.

## Processor System (PS) Performance Characteristics

Table 28: Processor Performance

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
F <sub>APUMAX</sub>	Maximum APU clock frequency.	1500	1333	1200	MHz
F <sub>RPUMAX</sub>	Maximum RPU clock frequency.	600	533	500	MHz
F <sub>GPUMAX</sub>	Maximum GPU clock frequency.	667	600	600	MHz

Table 29: Configuration and Security Unit Performance

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
F <sub>CSUCIBMAX</sub>	Maximum CSU crypto interface block frequency.	400	400	400	MHz

Table 30: PS DDR Performance

Memory Standard	Package	DRAM Type	Speed Grade						Units
			-3		-2		-1		
			Min	Max	Min	Max	Min	Max	
DDR4	All FFV packages, FBVB900, and SFVC784	Single rank component	664	2400	664	2400	664	2400	Mb/s
		1 rank DIMM <sup>(1)(2)</sup>	664	2133	664	2133	664	2133	Mb/s
		2 rank DIMM <sup>(1)(3)</sup>	664	1866	664	1866	664	1866	Mb/s
	SFVA625	Single rank component	664	2133	664	2133	664	2133	Mb/s
		1 rank DIMM <sup>(1)(2)</sup>	664	1866	664	1866	664	1866	Mb/s
		2 rank DIMM <sup>(1)(3)</sup>	664	1600	664	1600	664	1600	Mb/s
	SBVA484	Single rank component	664	1066	664	1066	664	1066	Mb/s
		1 rank DIMM <sup>(1)(2)</sup>	664	1066	664	1066	664	1066	Mb/s
		2 rank DIMM <sup>(1)(3)</sup>	664	1066	664	1066	664	1066	Mb/s
LPDDR4	All FFV packages, FBVB900 and SFVC784	Single die package <sup>(5)</sup>	664	2400	664	2400	664	2400	Mb/s
		Dual die package <sup>(4)(5)</sup>	664	2133	664	2133	664	2133	Mb/s
	SFVA625	Single die package <sup>(5)</sup>	664	2133	664	2133	664	2133	Mb/s
		Dual die package <sup>(4)(5)</sup>	664	1866	664	1866	664	1866	Mb/s
	SBVA484	Single die package <sup>(5)</sup>	664	1066	664	1066	664	1066	Mb/s
		Dual die package <sup>(4)(5)</sup>	664	1066	664	1066	664	1066	Mb/s

**Table 31: PS NAND NV-DDR Synchronous Performance**

Memory Standard	Mode	Speed Grade			Units
		-3	-2	-1	
		Max	Max	Max	
NV-DDR <sup>(1)</sup>	5	200	200	200	Mb/s
	4	166.6	166.6	166.6	Mb/s
	3	133.3	133.3	133.3	Mb/s
	2	100	100	100	Mb/s
	1	66.6	66.6	66.6	Mb/s
	0	40	40	40	Mb/s

**Notes:**

1. The PS NAND memory controller interface for NV-DDR switching characteristics meets the requirements of the ONFI 3.1 specification.

**Table 32: PS NAND SDR Asynchronous Performance**

Memory Standard	Mode	Speed Grade			Units
		-3	-2	-1	
		Max	Max	Max	
SDR <sup>(1)(2)</sup>	5	50	50	50	Mb/s
	4	40	40	40	Mb/s
	3	33.3	33.3	33.3	Mb/s
	2	28.5	28.5	28.5	Mb/s
	1	20	20	20	Mb/s
	0	10	10	10	Mb/s

**Notes:**

1. The PS NAND memory controller interface for SDR switching characteristics meets the requirements of the ONFI 3.1 specification.
2. The NAND controller reference clock frequency maximum is 83 MHz.

**Table 33: PS-PL Interface Performance**

Symbol	Description	Min	Max	Units
F <sub>EMIOGEMCLK</sub>	EMIO gigabit Ethernet controller maximum frequency.	–	125	MHz
F <sub>EMIOSDCLK</sub>	EMIO SD controller maximum frequency.	–	25	MHz
F <sub>EMIOSPICLK</sub>	EMIO SPI controller maximum frequency.	–	25	MHz
F <sub>EMIOTRACECLK</sub>	EMIO trace controller maximum frequency.	–	125	MHz
F <sub>FCIDMACLK</sub>	Flow control interface DMA maximum frequency.	–	333	MHz
F <sub>AXICLK</sub>	Maximum AXI interface performance.	–	333	MHz
F <sub>DPLIVEVIDEO</sub>	DisplayPort controller live video interface maximum frequency.	–	300	MHz

# PS Switching Characteristics

## PS Clocks

Table 34: PS Reference Clock Requirements<sup>(1)</sup>

Symbol	Description	Min	Typ	Max	Units
T <sub>RMSJPSCLK</sub>	PS_REF_CLK input RMS clock jitter.	–	–	3	ps
T <sub>PJPSCLK</sub>	PS_REF_CLK input period jitter (peak-to-peak). Number of clock cycles = 10,000	–	–	50	ps
T <sub>DCPSCLK</sub>	PS_REF_CLK duty cycle.	45	–	55	%
T <sub>RFPSCLK</sub>	PS_REF_CLK rise time (20%–80%) and fall time (80%–20%).	–	–	2.22	ns
F <sub>PSCLK</sub>	PS_REF_CLK frequency.	27	–	60	MHz

**Notes:**

1. The values in this table are applicable to alternative PS reference clock inputs ALT\_REF\_CLK, AUX\_REF\_CLK, and VIDEO\_CLK.

Table 35: PS RTC Crystal Requirements<sup>(1)</sup>

Symbol	Description	Min	Typ	Max	Units
F <sub>XTAL</sub>	Parallel resonance crystal frequency.	–	32.8	–	KHz
T <sub>FTXTAL</sub>	Frequency tolerance.	–20	–	20	ppm
C <sub>XTAL</sub>	Load capacitance for crystal parallel resonance.	–	12.5	–	pF
R <sub>ESR</sub>	Crystal ESR (16.8 and 19.2 MHz).	–	70	–	KΩ
C <sub>SHUNT</sub>	Crystal shunt capacitance.	–	1.4	–	pF

**Notes:**

1. Required board components: Feedback resistor = 4.7 MΩ, PCB and pad capacitance = 1.5 pF, C<sub>1</sub> and C<sub>2</sub> capacitance = 21 pF.

Table 36: PS PLL Switching Characteristics

Symbol	Description	Speed Grade			Units
		-3	-2	-1	
F <sub>LOCKPSPLL</sub>	PLL maximum lock time.	100	100	100	μs
F <sub>PSPLLMAX</sub>	PLL maximum output frequency.	1600	1600	1600	MHz
F <sub>PSPLLMIN</sub>	PLL minimum output frequency.	750	750	750	MHz
F <sub>PSPLLVCOMAX</sub>	PLL maximum VCO frequency.	3000	3000	3000	MHz
F <sub>PSPLLVCOMIN</sub>	PLL minimum VCO frequency.	1500	1500	1500	MHz

## PS Triple-timer Counter Interface

Table 54: Triple-timer Counter Interface

Symbol	Description	Min	Max	Units
$T_{PWTTCOCLK}$	Triple-timer counter output clock pulse width.	60.4	–	ns
$F_{TTCOCLK}$	Triple-timer counter output clock frequency.	–	16.5	MHz
$T_{TTCICLKL}$	Triple-timer counter input clock high pulse width.	$1.5 \times 1/F_{LPD\_LSBUS\_CTRLMAX}$	–	ns
$T_{TTCICLKH}$	Triple-timer counter input clock low pulse width.	$1.5 \times 1/F_{LPD\_LSBUS\_CTRLMAX}$	–	ns
$F_{TTCICLK}$	Triple-timer counter input clock frequency.	–	$F_{LPD\_LSBUS\_CTRLMAX}/3$	MHz

**Notes:**

1. All timing values assume an ideal external input clock. Your actual timing budget must account for additional external clock jitter.

## PS Watchdog Timer Interface

Table 55: Watchdog Timer Interface

Symbol	Description	Min	Max	Units
$F_{WDTCLK}$	Watchdog timer input clock frequency.	–	100	MHz

## Programmable Logic (PL) Performance Characteristics

This section provides the performance characteristics of some common functions and designs implemented in Zynq UltraScale+ MPSoC. These values are subject to the same guidelines as the [AC Switching Characteristics, page 22](#). In each table, the I/O bank type is either high performance (HP) or high density (HD).

Table 70: LVDS Component Mode Performance

Description	I/O Bank Type	Speed Grade and V <sub>CCINT</sub> Operating Voltages										Units
		0.90V		0.85V				0.72V				
		-3		-2		-1		-2		-1		
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
LVDS TX DDR (OSERDES 4:1, 8:1)	HP	0	1250	0	1250	0	1250	0	1250	0	1250	Mb/s
LVDS TX SDR (OSERDES 2:1, 4:1)	HP	0	625	0	625	0	625	0	625	0	625	Mb/s
LVDS RX DDR (ISERDES 1:4, 1:8) <sup>(1)</sup>	HP	0	1250	0	1250	0	1250	0	1250	0	1250	Mb/s
LVDS RX DDR	HD	0	250	0	250	0	250	0	250	0	250	Mb/s
LVDS RX SDR (ISERDES 1:2, 1:4) <sup>(1)</sup>	HP	0	625	0	625	0	625	0	625	0	625	Mb/s
LVDS RX SDR	HD	0	125	0	125	0	125	0	125	0	125	Mb/s

### Notes:

1. LVDS receivers are typically bounded with certain applications to achieve maximum performance. Package skews are not included and should be removed through PCB routing.

Table 71: LVDS Native Mode Performance<sup>(1)(2)</sup>

Description	DATA_WIDTH	I/O Bank Type	Speed Grade and V <sub>CCINT</sub> Operating Voltages										Units
			0.90V		0.85V				0.72V				
			-3 <sup>(3)</sup>		-2 <sup>(3)</sup>		-1		-2 <sup>(3)</sup>		-1		
			Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
LVDS TX DDR (TX_BITSLICE)	4	HP	375	1600	375	1600	375	1260	375	1400	375	1260	Mb/s
	8		375	1600	375	1600	375	1260	375	1600	375	1260	Mb/s
LVDS TX SDR (TX_BITSLICE)	4	HP	187.5	800	187.5	800	187.5	630	187.5	700	187.5	630	Mb/s
	8		187.5	800	187.5	800	187.5	630	187.5	800	187.5	630	Mb/s
LVDS RX DDR (RX_BITSLICE) <sup>(4)</sup>	4	HP	375	1600	375	1600	375	1260	375	1400	375	1260	Mb/s
	8		375	1600	375	1600	375	1260	375	1600	375	1260	Mb/s
LVDS RX SDR (RX_BITSLICE) <sup>(4)</sup>	4	HP	187.5	800	187.5	800	187.5	630	187.5	700	187.5	630	Mb/s
	8		187.5	800	187.5	800	187.5	630	187.5	800	187.5	630	Mb/s

### Notes:

1. Native mode is supported through the [High-Speed SelectIO Interface Wizard](#) available with the Vivado Design Suite. The performance values assume a source-synchronous interface.
2. PLL settings can restrict the minimum allowable data rate. For example, when using the PLL with CLKOUTPHY\_MODE = VCO\_HALF the minimum frequency is PLL\_F<sub>VCOMIN</sub>/2.
3. In the SBVA484 package, the maximum data rate is 1260 Mb/s for DDR interfaces and 630 Mb/s for SDR interfaces.
4. LVDS receivers are typically bounded with certain applications to achieve maximum performance. Package skews are not included and should be removed through PCB routing.

Table 75: IOB High Density (HD) Switching Characteristics (Cont'd)

I/O Standards	T <sub>INBUF_DELAY_PAD_I</sub>					T <sub>OUTBUF_DELAY_O_PAD</sub>					T <sub>OUTBUF_DELAY_TD_PAD</sub>					Units
	0.90V		0.85V		0.72V	0.90V		0.85V		0.72V	0.90V		0.85V		0.72V	
	-3	-2	-1	-2	-1	-3	-2	-1	-2	-1	-3	-2	-1	-2	-1	
HSTL_I_F	0.856	0.856	0.900	0.856	0.900	1.611	1.611	1.762	1.611	1.762	1.313	1.313	1.417	1.313	1.417	ns
HSTL_I_S	0.856	0.856	0.900	0.856	0.900	1.798	1.798	1.913	1.798	1.913	1.630	1.630	1.780	1.630	1.780	ns
HSUL_12_F	0.780	0.780	0.867	0.780	0.867	1.573	1.573	1.703	1.573	1.703	1.222	1.222	1.335	1.222	1.335	ns
HSUL_12_S	0.780	0.780	0.867	0.780	0.867	1.711	1.711	1.864	1.711	1.864	1.536	1.536	1.665	1.536	1.665	ns
LVC MOS12_F_12	0.918	0.918	0.976	0.918	0.976	1.689	1.689	1.856	1.689	1.856	1.202	1.202	1.317	1.202	1.317	ns
LVC MOS12_F_4	0.918	0.918	0.976	0.918	0.976	1.742	1.742	1.922	1.742	1.922	1.353	1.353	1.478	1.353	1.478	ns
LVC MOS12_F_8	0.918	0.918	0.976	0.918	0.976	1.714	1.714	1.879	1.714	1.879	1.292	1.292	1.432	1.292	1.432	ns
LVC MOS12_S_12	0.918	0.918	0.976	0.918	0.976	2.073	2.073	2.247	2.073	2.247	1.581	1.581	1.717	1.581	1.717	ns
LVC MOS12_S_4	0.918	0.918	0.976	0.918	0.976	1.979	1.979	2.182	1.979	2.182	1.633	1.633	1.772	1.633	1.772	ns
LVC MOS12_S_8	0.918	0.918	0.976	0.918	0.976	2.205	2.205	2.406	2.205	2.406	1.767	1.767	1.928	1.767	1.928	ns
LVC MOS15_F_12	0.905	0.905	0.958	0.905	0.958	1.713	1.713	1.892	1.713	1.892	1.275	1.275	1.428	1.275	1.428	ns
LVC MOS15_F_16	0.905	0.905	0.958	0.905	0.958	1.722	1.722	1.881	1.722	1.881	1.260	1.260	1.407	1.260	1.407	ns
LVC MOS15_F_4	0.905	0.905	0.958	0.905	0.958	1.825	1.825	1.959	1.825	1.959	1.453	1.453	1.557	1.453	1.557	ns
LVC MOS15_F_8	0.905	0.905	0.958	0.905	0.958	1.778	1.778	1.930	1.778	1.930	1.378	1.378	1.458	1.378	1.458	ns
LVC MOS15_S_12	0.905	0.905	0.958	0.905	0.958	1.991	1.991	2.139	1.991	2.139	1.516	1.516	1.648	1.516	1.648	ns
LVC MOS15_S_16	0.905	0.905	0.958	0.905	0.958	2.172	2.172	2.389	2.172	2.389	1.707	1.707	1.888	1.707	1.888	ns
LVC MOS15_S_4	0.905	0.905	0.958	0.905	0.958	2.313	2.313	2.483	2.313	2.483	1.952	1.952	2.123	1.952	2.123	ns
LVC MOS15_S_8	0.905	0.905	0.958	0.905	0.958	2.170	2.170	2.400	2.170	2.400	1.817	1.817	1.984	1.817	1.984	ns
LVC MOS18_F_12	0.915	0.915	0.958	0.915	0.958	1.805	1.805	1.962	1.805	1.962	1.383	1.383	1.471	1.383	1.471	ns
LVC MOS18_F_16	0.915	0.915	0.958	0.915	0.958	1.785	1.785	1.917	1.785	1.917	1.338	1.338	1.446	1.338	1.446	ns
LVC MOS18_F_4	0.915	0.915	0.958	0.915	0.958	1.868	1.868	2.013	1.868	2.013	1.472	1.472	1.599	1.472	1.599	ns
LVC MOS18_F_8	0.915	0.915	0.958	0.915	0.958	1.797	1.797	1.979	1.797	1.979	1.384	1.384	1.487	1.384	1.487	ns
LVC MOS18_S_12	0.915	0.915	0.958	0.915	0.958	2.201	2.201	2.408	2.201	2.408	1.762	1.762	1.894	1.762	1.894	ns
LVC MOS18_S_16	0.915	0.915	0.958	0.915	0.958	2.173	2.173	2.362	2.173	2.362	1.702	1.702	1.834	1.702	1.834	ns
LVC MOS18_S_4	0.915	0.915	0.958	0.915	0.958	2.346	2.346	2.567	2.346	2.567	1.951	1.951	2.092	1.951	2.092	ns
LVC MOS18_S_8	0.915	0.915	0.958	0.915	0.958	2.292	2.292	2.511	2.292	2.511	1.848	1.848	2.008	1.848	2.008	ns
LVC MOS25_F_12	0.988	0.988	1.042	0.988	1.042	2.153	2.153	2.453	2.153	2.453	1.692	1.692	1.856	1.692	1.856	ns
LVC MOS25_F_16	0.988	0.988	1.042	0.988	1.042	2.105	2.105	2.406	2.105	2.406	1.623	1.623	1.786	1.623	1.786	ns
LVC MOS25_F_4	0.988	0.988	1.042	0.988	1.042	2.344	2.344	2.554	2.344	2.554	1.842	1.842	2.039	1.842	2.039	ns
LVC MOS25_F_8	0.988	0.988	1.042	0.988	1.042	2.184	2.184	2.516	2.184	2.516	1.726	1.726	1.910	1.726	1.910	ns
LVC MOS25_S_12	0.988	0.988	1.042	0.988	1.042	2.558	2.558	2.840	2.558	2.840	1.971	1.971	2.194	1.971	2.194	ns
LVC MOS25_S_16	0.988	0.988	1.042	0.988	1.042	2.449	2.449	2.740	2.449	2.740	1.852	1.852	2.063	1.852	2.063	ns
LVC MOS25_S_4	0.988	0.988	1.042	0.988	1.042	2.770	2.770	3.066	2.770	3.066	2.224	2.224	2.458	2.224	2.458	ns
LVC MOS25_S_8	0.988	0.988	1.042	0.988	1.042	2.663	2.663	2.963	2.663	2.963	2.091	2.091	2.373	2.091	2.373	ns
LVC MOS33_F_12	1.154	1.154	1.213	1.154	1.213	2.415	2.415	2.651	2.415	2.651	1.754	1.754	1.915	1.754	1.915	ns
LVC MOS33_F_16	1.154	1.154	1.213	1.154	1.213	2.383	2.383	2.603	2.383	2.603	1.734	1.734	1.869	1.734	1.869	ns
LVC MOS33_F_4	1.154	1.154	1.213	1.154	1.213	2.541	2.541	2.765	2.541	2.765	1.932	1.932	2.135	1.932	2.135	ns
LVC MOS33_F_8	1.154	1.154	1.213	1.154	1.213	2.603	2.603	2.822	2.603	2.822	1.937	1.937	2.130	1.937	2.130	ns
LVC MOS33_S_12	1.154	1.154	1.213	1.154	1.213	2.705	2.705	3.047	2.705	3.047	2.049	2.049	2.318	2.049	2.318	ns
LVC MOS33_S_16	1.154	1.154	1.213	1.154	1.213	2.714	2.714	3.024	2.714	3.024	2.028	2.028	2.232	2.028	2.232	ns
LVC MOS33_S_4	1.154	1.154	1.213	1.154	1.213	2.999	2.999	3.340	2.999	3.340	2.320	2.320	2.610	2.320	2.610	ns

Table 76: IOB High Performance (HP) Switching Characteristics (Cont'd)

I/O Standards	T <sub>INBUF_DELAY_PAD_I</sub>					T <sub>OUTBUF_DELAY_O_PAD</sub>					T <sub>OUTBUF_DELAY_TD_PAD</sub>					Units
	0.90V		0.85V		0.72V	0.90V		0.85V		0.72V	0.90V		0.85V		0.72V	
	-3	-2	-1	-2	-1	-3	-2	-1	-2	-1	-3	-2	-1	-2	-1	
SSTL135_DCI_S	0.366	0.366	0.399	0.366	0.399	0.746	0.746	0.799	0.746	0.799	0.829	0.829	0.893	0.829	0.893	ns
SSTL135_F	0.378	0.378	0.399	0.378	0.399	0.408	0.408	0.428	0.408	0.428	0.528	0.528	0.561	0.528	0.561	ns
SSTL135_M	0.378	0.378	0.399	0.378	0.399	0.555	0.555	0.585	0.555	0.585	0.641	0.641	0.679	0.641	0.679	ns
SSTL135_S	0.378	0.378	0.399	0.378	0.399	0.772	0.772	0.823	0.772	0.823	0.827	0.827	0.878	0.827	0.878	ns
SSTL15_DCI_F	0.402	0.402	0.417	0.402	0.417	0.412	0.412	0.429	0.412	0.429	0.531	0.531	0.563	0.531	0.563	ns
SSTL15_DCI_M	0.402	0.402	0.417	0.402	0.417	0.553	0.553	0.583	0.553	0.583	0.645	0.645	0.685	0.645	0.685	ns
SSTL15_DCI_S	0.402	0.402	0.417	0.402	0.417	0.768	0.768	0.822	0.768	0.822	0.847	0.847	0.912	0.847	0.912	ns
SSTL15_F	0.371	0.371	0.400	0.371	0.400	0.408	0.408	0.428	0.408	0.428	0.530	0.530	0.556	0.530	0.556	ns
SSTL15_M	0.371	0.371	0.400	0.371	0.400	0.554	0.554	0.585	0.554	0.585	0.639	0.639	0.677	0.639	0.677	ns
SSTL15_S	0.371	0.371	0.400	0.371	0.400	0.767	0.767	0.817	0.767	0.817	0.813	0.813	0.867	0.813	0.867	ns
SSTL18_I_DCI_F	0.329	0.329	0.336	0.329	0.336	0.445	0.445	0.461	0.445	0.461	0.566	0.566	0.595	0.566	0.595	ns
SSTL18_I_DCI_M	0.329	0.329	0.336	0.329	0.336	0.554	0.554	0.585	0.554	0.585	0.644	0.644	0.683	0.644	0.683	ns
SSTL18_I_DCI_S	0.329	0.329	0.336	0.329	0.336	0.762	0.762	0.818	0.762	0.818	0.837	0.837	0.899	0.837	0.899	ns
SSTL18_I_F	0.316	0.316	0.337	0.316	0.337	0.454	0.454	0.476	0.454	0.476	0.578	0.578	0.608	0.578	0.608	ns
SSTL18_I_M	0.316	0.316	0.337	0.316	0.337	0.571	0.571	0.603	0.571	0.603	0.652	0.652	0.692	0.652	0.692	ns
SSTL18_I_S	0.316	0.316	0.337	0.316	0.337	0.782	0.782	0.835	0.782	0.835	0.816	0.816	0.870	0.816	0.870	ns
SUB_LVDS	0.539	0.539	0.620	0.539	0.620	0.660	0.660	0.692	0.660	0.692	969.863	969.863	969.863	969.863	969.863	ns

### IOB 3-state Output Switching Characteristics

Table 77 specifies the values of T<sub>OUTBUF\_DELAY\_TE\_PAD</sub> and T<sub>INBUF\_DELAY\_IBUFDIS\_O</sub>. T<sub>OUTBUF\_DELAY\_TE\_PAD</sub> is the delay from the T pin to the IOB pad through the output buffer of an IOB pad, when 3-state is enabled (i.e., a high impedance state). T<sub>INBUF\_DELAY\_IBUFDIS\_O</sub> is the IOB delay from IBUFDISABLE to O output. In HP I/O banks, the internal DCI termination turn-off time is always faster than T<sub>OUTBUF\_DELAY\_TE\_PAD</sub> when the DCITERMDISABLE pin is used. In HD I/O banks, the internal IN\_TERM termination turn-off time is always faster than T<sub>OUTBUF\_DELAY\_TE\_PAD</sub> when the INTERMDISABLE pin is used.

Table 77: IOB 3-state Output Switching Characteristics

Symbol	Description	Speed Grade and V <sub>CCINT</sub> Operating Voltages					Units
		0.90V		0.85V		0.72V	
		-3	-2	-1	-2	-1	
T <sub>OUTBUF_DELAY_TE_PAD</sub>	T input to pad high-impedance for HD I/O banks	6.318	6.318	6.369	6.318	6.369	ns
	T input to pad high-impedance for HP I/O banks	5.330	5.330	5.341	5.330	5.341	ns
T <sub>INBUF_DELAY_IBUFDIS_O</sub>	IBUF turn-on time from IBUFDISABLE to O output for HD I/O banks	2.266	2.266	2.430	2.266	2.430	ns
	IBUF turn-on time from IBUFDISABLE to O output for HP I/O banks	0.936	0.936	1.037	0.936	1.037	ns

## MMCM Switching Characteristics

Table 85: MMCM Specification

Symbol	Description	Speed Grade and V <sub>CCINT</sub> Operating Voltages					Units
		0.90V	0.85V		0.72V		
		-3	-2	-1	-2	-1	
MMCM_F <sub>INMAX</sub>	Maximum input clock frequency.	1066	933	800	933	800	MHz
MMCM_F <sub>INMIN</sub>	Minimum input clock frequency.	10	10	10	10	10	MHz
MMCM_F <sub>INJITTER</sub>	Maximum input clock period jitter.	< 20% of clock input period or 1 ns Max					
MMCM_F <sub>INDUTY</sub>	Input duty cycle range: 10–49 MHz.	25–75					%
	Input duty cycle range: 50–199 MHz.	30–70					%
	Input duty cycle range: 200–399 MHz.	35–65					%
	Input duty cycle range: 400–499 MHz.	40–60					%
	Input duty cycle range: >500 MHz.	45–55					%
MMCM_F <sub>MIN_PSCLK</sub>	Minimum dynamic phase shift clock frequency.	0.01	0.01	0.01	0.01	0.01	MHz
MMCM_F <sub>MAX_PSCLK</sub>	Maximum dynamic phase shift clock frequency.	550	500	450	500	450	MHz
MMCM_F <sub>VCOMIN</sub>	Minimum MMCM VCO frequency.	800	800	800	800	800	MHz
MMCM_F <sub>VCOMAX</sub>	Maximum MMCM VCO frequency.	1600	1600	1600	1600	1600	MHz
MMCM_F <sub>BANDWIDTH</sub>	Low MMCM bandwidth at typical. <sup>(1)</sup>	1.00	1.00	1.00	1.00	1.00	MHz
	High MMCM bandwidth at typical. <sup>(1)</sup>	4.00	4.00	4.00	4.00	4.00	MHz
MMCM_T <sub>STATPHAOFFSET</sub>	Static phase offset of the MMCM outputs. <sup>(2)</sup>	0.12	0.12	0.12	0.12	0.12	ns
MMCM_T <sub>OUTJITTER</sub>	MMCM output jitter.	Note 3					
MMCM_T <sub>OUTDUTY</sub>	MMCM output clock duty cycle precision. <sup>(4)</sup>	0.165	0.20	0.20	0.20	0.20	ns
MMCM_T <sub>LOCKMAX</sub>	MMCM maximum lock time for MMCM_F <sub>PFDMIN</sub> .	100	100	100	100	100	μs
MMCM_F <sub>OUTMAX</sub>	MMCM maximum output frequency.	891	775	667	725	667	MHz
MMCM_F <sub>OUTMIN</sub>	MMCM minimum output frequency. <sup>(4)(5)</sup>	6.25	6.25	6.25	6.25	6.25	MHz
MMCM_T <sub>EXTFDVAR</sub>	External clock feedback variation.	< 20% of clock input period or 1 ns Max					
MMCM_RST <sub>MINPULSE</sub>	Minimum reset pulse width.	5.00	5.00	5.00	5.00	5.00	ns
MMCM_F <sub>PFDMAX</sub>	Maximum frequency at the phase frequency detector.	550	500	450	500	450	MHz
MMCM_F <sub>PFDMIN</sub>	Minimum frequency at the phase frequency detector.	10	10	10	10	10	MHz
MMCM_T <sub>FBDELAY</sub>	Maximum delay in the feedback path.	5 ns Max or one clock cycle					

Table 85: MMCM Specification (Cont'd)

Symbol	Description	Speed Grade and V <sub>CCINT</sub> Operating Voltages					Units
		0.90V	0.85V		0.72V		
		-3	-2	-1	-2	-1	
MMCM_F <sub>DPRCLK_MAX</sub>	Maximum DRP clock frequency	250	250	250	250	250	MHz

**Notes:**

1. The MMCM does not filter typical spread-spectrum input clocks because they are usually far below the bandwidth filter frequencies.
2. The static offset is measured between any MMCM outputs with identical phase.
3. Values for this parameter are available in the Clocking Wizard.
4. Includes global clock buffer.
5. Calculated as  $F_{VCO}/128$  assuming output duty cycle is 50%.

# GTH Transceiver Specifications

The *UltraScale Architecture and Product Overview* ([DS890](#)) lists the Zynq UltraScale+ MPSoCs that include the GTH transceivers.

## GTH Transceiver DC Input and Output Levels

[Table 94](#) summarizes the DC specifications of the GTH transceivers in Zynq UltraScale+ MPSoC. Consult the *UltraScale Architecture GTH Transceiver User Guide* ([UG576](#)) for further details.

Table 94: GTH Transceiver DC Specifications

Symbol	DC Parameter	Conditions	Min	Typ	Max	Units
DV <sub>PPIN</sub>	Differential peak-to-peak input voltage (external AC coupled).	> 10.3125 Gb/s	150	–	1250	mV
		6.6 Gb/s to 10.3125 Gb/s	150	–	1250	mV
		≤ 6.6 Gb/s	150	–	2000	mV
V <sub>IN</sub>	Single-ended input voltage. Voltage measured at the pin referenced to GND.	DC coupled V <sub>MGTAVTT</sub> = 1.2V	–400	–	V <sub>MGTAVTT</sub>	mV
V <sub>CMIN</sub>	Common mode input voltage.	DC coupled V <sub>MGTAVTT</sub> = 1.2V	–	2/3 V <sub>MGTAVTT</sub>	–	mV
D <sub>VPPOUT</sub>	Differential peak-to-peak output voltage. <sup>(1)</sup>	Transmitter output swing is set to 11111	800	–	–	mV
V <sub>CMOUTDC</sub>	Common mode output voltage: DC coupled (equation based).	When remote RX is terminated to GND	$V_{MGTAVTT}/2 - D_{VPPOUT}/4$			mV
		When remote RX termination is floating	$V_{MGTAVTT} - D_{VPPOUT}/2$			mV
		When remote RX is terminated to V <sub>RX_TERM</sub> <sup>(2)</sup>	$V_{MGTAVTT} - \frac{D_{VPPOUT}}{4} - \left(\frac{V_{MGTAVTT} - V_{RX\_TERM}}{2}\right)$			mV
V <sub>CMOUTAC</sub>	Common mode output voltage: AC coupled (equation based).		$V_{MGTAVTT} - D_{VPPOUT}/2$			mV
R <sub>IN</sub>	Differential input resistance.		–	100	–	Ω
R <sub>OUT</sub>	Differential output resistance.		–	100	–	Ω
T <sub>OSKEW</sub>	Transmitter output pair (TXP and TXN) intra-pair skew (all packages).		–	–	10	ps
C <sub>EXT</sub>	Recommended external AC coupling capacitor. <sup>(3)</sup>		–	100	–	nF

**Notes:**

1. The output swing and pre-emphasis levels are programmable using the attributes discussed in the *UltraScale Architecture GTH Transceiver User Guide* ([UG576](#)), and can result in values lower than reported in this table.
2. V<sub>RX\_TERM</sub> is the remote RX termination voltage.
3. Other values can be used as appropriate to conform to specific protocols and standards.

**Table 105: GTH Transceiver Protocol List**

Protocol	Specification	Serial Rate (Gb/s)	Electrical Compliance
CAUI-10	IEEE 802.3-2012	10.3125	Compliant
nPPI	IEEE 802.3-2012	10.3125	Compliant
10GBASE-KR <sup>(1)</sup>	IEEE 802.3-2012	10.3125	Compliant
40GBASE-KR	IEEE 802.3-2012	10.3125	Compliant
SFP+	SFF-8431 (SR and LR)	9.95328–11.10	Compliant
XFP	INF-8077i, revision 4.5	10.3125	Compliant
RXAUI	CEI-6G-SR	6.25	Compliant
XAUI	IEEE 802.3-2012	3.125	Compliant
1000BASE-X	IEEE 802.3-2012	1.25	Compliant
5.0G Ethernet	IEEE 802.3bx (PAR)	5	Compliant
2.5G Ethernet	IEEE 802.3bx (PAR)	2.5	Compliant
HiGig, HiGig+, HiGig2	IEEE 802.3-2012	3.74, 6.6	Compliant
OTU2	ITU G.8251	10.709225	Compliant
OTU4 (OTL4.10)	OIF-CEI-11G-SR	11.180997	Compliant
OC-3/12/48/192	GR-253-CORE	0.1555–9.956	Compliant
TFI-5	OIF-TFI5-0.1.0	2.488	Compliant
Interlaken	OIF-CEI-6G, OIF-CEI-11G-SR	4.25–12.5	Compliant
PCIe Gen1, 2, 3	PCI Express base 3.0	2.5, 5.0, and 8.0	Compliant
SDI <sup>(2)</sup>	SMPTE 424M-2006	0.27–2.97	Compliant
UHD-SDI <sup>(2)</sup>	SMPTE ST-2081 6G, SMPTE ST-2082 12G	6 and 12	Compliant
Hybrid memory cube (HMC)	HMC-15G-SR	10, 12.5, and 15.0	Compliant
MoSys Bandwidth Engine	CEI-11-SR and CEI-11-SR (overclocked)	10.3125, 15.5	Compliant
CPRI	CPRI_v_6_1_2014-07-01	0.6144–12.165	Compliant
HDMI <sup>(2)</sup>	HDMI 2.0	All	Compliant
Passive optical network (PON)	10G-EPON, 1G-EPON, NG-PON2, XG-PON, and 2.5G-PON	0.155–10.3125	Compliant
JESD204a/b	OIF-CEI-6G, OIF-CEI-11G	3.125–12.5	Compliant
Serial RapidIO	RapidIO specification 3.1	1.25–10.3125	Compliant
DisplayPort <sup>(2)</sup>	DP 1.2B CTS	1.62–5.4	Compliant
Fibre channel	FC-PI-4	1.0625–14.025	Compliant
SATA Gen1, 2, 3	Serial ATA revision 3.0 specification	1.5, 3.0, and 6.0	Compliant
SAS Gen1, 2, 3	T10/BSR INCITS 519	3.0, 6.0, and 12.0	Compliant
SFI-5	OIF-SFI5-01.0	0.625–12.5	Compliant
Aurora	CEI-6G, CEI-11G-LR	up to 11.180997	Compliant

**Notes:**

1. The transition time of the transmitter is faster than the IEEE Std 802.3-2012 specification.
2. This protocol requires external circuitry to achieve compliance.

Table 114: GTY Transceiver User Clock Switching Characteristics<sup>(1)</sup> (Cont'd)

Symbol	Description	Data Width Conditions (Bit)		Speed Grade and V <sub>CCINT</sub> Operating Voltages					Units
				0.90V		0.85V		0.72V	
		Internal Logic	Interconnect Logic	-3 <sup>(2)</sup>	-2 <sup>(2)(3)</sup>	-1 <sup>(4)(5)</sup>	-2 <sup>(3)</sup>	-1 <sup>(5)</sup>	
F <sub>TXIN2</sub>	TXUSRCLK2 <sup>(6)</sup> maximum frequency	16	16	511.719	511.719	390.625	390.625	322.266	MHz
		16	32	255.859	255.859	195.313	195.313	161.133	MHz
		32	32	511.719	511.719	390.625	390.625	322.266	MHz
		32	64	255.859	255.859	195.313	195.313	161.133	MHz
		64	64	511.719	440.781	402.832	402.832	195.313	MHz
		64	128	255.859	220.391	201.416	201.416	97.656	MHz
		20	20	409.375	409.375	312.500	312.500	257.813	MHz
		20	40	204.688	204.688	156.250	156.250	128.906	MHz
		40	40	409.375	409.375	312.500	350.000	257.813	MHz
		40	80	204.688	204.688	156.250	175.000	128.906	MHz
		80	80	409.375	352.625	322.266	352.625	156.250	MHz
80	160	204.688	176.313	161.133	176.313	78.125	MHz		
F <sub>RXIN2</sub>	RXUSRCLK2 <sup>(6)</sup> maximum frequency	16	16	511.719	511.719	390.625	390.625	322.266	MHz
		16	32	255.859	255.859	195.313	195.313	161.133	MHz
		32	32	511.719	511.719	390.625	390.625	322.266	MHz
		32	64	255.859	255.859	195.313	195.313	161.133	MHz
		64	64	511.719	440.781	402.832	402.832	195.313	MHz
		64	128	255.859	220.391	201.416	201.416	97.656	MHz
		20	20	409.375	409.375	312.500	312.500	257.813	MHz
		20	40	204.688	204.688	156.250	156.250	128.906	MHz
		40	40	409.375	409.375	312.500	350.000	257.813	MHz
		40	80	204.688	204.688	156.250	175.000	128.906	MHz
		80	80	409.375	352.625	322.266	352.625	156.250	MHz
80	160	204.688	176.313	161.133	176.313	78.125	MHz		

**Notes:**

1. Clocking must be implemented as described in the *UltraScale Architecture GTY Transceiver User Guide* ([UG578](#)).
2. For speed grades -3E, -2E, and -2I, a 16-bit and 20-bit internal data path can only be used for line rates less than 8.1875 Gb/s.
3. For speed grade -2LE, a 16-bit and 20-bit internal data path can only be used for line rates less than 8.1875 Gb/s when V<sub>CCINT</sub> = 0.85V or 6.25 Gb/s when V<sub>CCINT</sub> = 0.72V.
4. For speed grades -1E and -1I, a 16-bit and 20-bit internal data path can only be used for line rates less than 6.25 Gb/s.
5. For speed grade -1LI, a 16-bit and 20-bit internal data path can only be used for line rates less than 6.25 Gb/s when V<sub>CCINT</sub> = 0.85V or 5.15625 Gb/s when V<sub>CCINT</sub> = 0.72V.
6. When the gearbox is used, these maximums refer to the XCLK. For more information, see the *Valid Data Width Combinations for TX Asynchronous Gearbox* table in the *UltraScale Architecture GTY Transceiver User Guide* ([UG578](#)).

**Table 115: GTY Transceiver Transmitter Switching Characteristics**

Symbol	Description	Condition	Min	Typ	Max	Units
F <sub>GTYTX</sub>	Serial data rate range		0.500	–	F <sub>GTYMAX</sub>	Gb/s
T <sub>RTX</sub>	TX rise time	20%–80%	–	21	–	ps
T <sub>FTX</sub>	TX fall time	80%–20%	–	21	–	ps
T <sub>LLSKEW</sub>	TX lane-to-lane skew <sup>(1)</sup>		–	–	500.00	ps
T <sub>J32.75</sub>	Total jitter <sup>(2)(4)</sup>	32.75 Gb/s	–	–	0.35	UI
D <sub>J32.75</sub>	Deterministic jitter <sup>(2)(4)</sup>		–	–	0.19	UI
T <sub>J28.21</sub>	Total jitter <sup>(2)(4)</sup>	28.21 Gb/s	–	–	0.28	UI
D <sub>J28.21</sub>	Deterministic jitter <sup>(2)(4)</sup>		–	–	0.17	UI
T <sub>J16.375</sub>	Total jitter <sup>(2)(4)</sup>	16.375 Gb/s	–	–	0.28	UI
D <sub>J16.375</sub>	Deterministic jitter <sup>(2)(4)</sup>		–	–	0.17	UI
T <sub>J15.0</sub>	Total jitter <sup>(2)(4)</sup>	15.0 Gb/s	–	–	0.28	UI
D <sub>J15.0</sub>	Deterministic jitter <sup>(2)(4)</sup>		–	–	0.17	UI
T <sub>J14.1</sub>	Total jitter <sup>(2)(4)</sup>	14.1 Gb/s	–	–	0.28	UI
D <sub>J14.1</sub>	Deterministic jitter <sup>(2)(4)</sup>		–	–	0.17	UI
T <sub>J14.1</sub>	Total jitter <sup>(2)(4)</sup>	14.025 Gb/s	–	–	0.28	UI
D <sub>J14.1</sub>	Deterministic jitter <sup>(2)(4)</sup>		–	–	0.17	UI
T <sub>J13.1</sub>	Total jitter <sup>(2)(4)</sup>	13.1 Gb/s	–	–	0.28	UI
D <sub>J13.1</sub>	Deterministic jitter <sup>(2)(4)</sup>		–	–	0.17	UI
T <sub>J12.5_QPLL</sub>	Total jitter <sup>(2)(4)</sup>	12.5 Gb/s	–	–	0.28	UI
D <sub>J12.5_QPLL</sub>	Deterministic jitter <sup>(2)(4)</sup>		–	–	0.17	UI
T <sub>J12.5_CPLL</sub>	Total jitter <sup>(3)(4)</sup>	12.5 Gb/s	–	–	0.33	UI
D <sub>J12.5_CPLL</sub>	Deterministic jitter <sup>(3)(4)</sup>		–	–	0.17	UI
T <sub>J11.3_QPLL</sub>	Total jitter <sup>(2)(4)</sup>	11.3 Gb/s	–	–	0.28	UI
D <sub>J11.3_QPLL</sub>	Deterministic jitter <sup>(2)(4)</sup>		–	–	0.17	UI
T <sub>J10.3125_QPLL</sub>	Total jitter <sup>(2)(4)</sup>	10.3125 Gb/s	–	–	0.28	UI
D <sub>J10.3125_QPLL</sub>	Deterministic jitter <sup>(2)(4)</sup>		–	–	0.17	UI
T <sub>J10.3125_CPLL</sub>	Total jitter <sup>(3)(4)</sup>	10.3125 Gb/s	–	–	0.33	UI
D <sub>J10.3125_CPLL</sub>	Deterministic jitter <sup>(3)(4)</sup>		–	–	0.17	UI
T <sub>J9.953_QPLL</sub>	Total jitter <sup>(2)(4)</sup>	9.953 Gb/s	–	–	0.28	UI
D <sub>J9.953_QPLL</sub>	Deterministic jitter <sup>(2)(4)</sup>		–	–	0.17	UI
T <sub>J9.953_CPLL</sub>	Total jitter <sup>(3)(4)</sup>	9.953 Gb/s	–	–	0.33	UI
D <sub>J9.953_CPLL</sub>	Deterministic jitter <sup>(3)(4)</sup>		–	–	0.17	UI
T <sub>J8.0</sub>	Total jitter <sup>(3)(4)</sup>	8.0 Gb/s	–	–	0.32	UI
D <sub>J8.0</sub>	Deterministic jitter <sup>(3)(4)</sup>		–	–	0.17	UI
T <sub>J6.6</sub>	Total jitter <sup>(3)(4)</sup>	6.6 Gb/s	–	–	0.30	UI
D <sub>J6.6</sub>	Deterministic jitter <sup>(3)(4)</sup>		–	–	0.15	UI
T <sub>J5.0</sub>	Total jitter <sup>(3)(4)</sup>	5.0 Gb/s	–	–	0.30	UI
D <sub>J5.0</sub>	Deterministic jitter <sup>(3)(4)</sup>		–	–	0.15	UI
T <sub>J4.25</sub>	Total jitter <sup>(3)(4)</sup>	4.25 Gb/s	–	–	0.30	UI
D <sub>J4.25</sub>	Deterministic jitter <sup>(3)(4)</sup>		–	–	0.15	UI

Table 117: GTY Transceiver Protocol List (Cont'd)

Protocol	Specification	Serial Rate (Gb/s)	Electrical Compliance
Serial RapidIO	RapidIO specification 3.1	1.25–10.3125	Compliant
DisplayPort	DP 1.2B CTS	1.62–5.4	Compliant <sup>(3)</sup>
Fibre channel	FC-PI-4	1.0625–14.025	Compliant
SATA Gen1, 2, 3	Serial ATA revision 3.0 specification	1.5, 3.0, and 6.0	Compliant
SAS Gen1, 2, 3	T10/BSR INCITS 519	3.0, 6.0, and 12.0	Compliant
SFI-5	OIF-SFI5-01.0	0.625 - 12.5	Compliant
Aurora	CEI-6G, CEI-11G-LR	All rates	Compliant

**Notes:**

1. 25 dB loss at Nyquist without FEC.
2. The transition time of the transmitter is faster than the IEEE Std 802.3-2012 specification.
3. This protocol requires external circuitry to achieve compliance.

# Configuration Switching Characteristics

Table 127: Configuration Switching Characteristics

Symbol	Description	Speed Grade and V <sub>CCINT</sub> Operating Voltages					Units
		0.90V	0.85V		0.72V		
		-3	-2	-1	-2	-1	
<b>PL Power-up Timing Characteristics</b>							
T <sub>PL</sub>	PS_PROG_B PL latency.	7.5	7.5	7.5	7.5	7.5	ms, Max
T <sub>POR</sub>	Power-on reset from PL power-on to PL ready to configure (40 ms maximum ramp rate).	65	65	65	65	65	ms, Max
		0	0	0	0	0	ms, Min
	Power-on reset from PL power-on to PL ready to configure with POR override (2 ms maximum ramp rate).	15	15	15	15	15	ms, Max
		5	5	5	5	5	ms, Min
T <sub>PS_PROG_B</sub>	PL program pulse width.	250	250	250	250	250	ns, Min
<b>Internal Configuration Access Port</b>							
F <sub>ICAPCK</sub>	Internal configuration access port (ICAPE3).	200	200	200	150	150	MHz, Max
<b>DNA Port Switching</b>							
F <sub>DNACK</sub>	DNA port frequency (DNA_PORT).	200	200	200	175	175	MHz, Max
<b>STARTUPE3 Ports</b>							
F <sub>CFGMCLK</sub>	STARTUPE3 CFGMCLK output frequency.	50.00	50.00	50.00	50.00	50.00	MHz, Typ
F <sub>CFGMCLKTOL</sub>	STARTUPE3 CFGMCLK output frequency tolerance.	±15	±15	±15	±15	±15	%, Max
T <sub>DCI_MATCH</sub>	Specifies a stall in the startup cycle until the digitally controlled impedance (DCI) match signals are asserted.	4	4	4	4	4	ms, Max